NM93CS06/CS46/CS56/CS66 (MICROWIRE™ Bus Interface) 256-/1024-/2048-/4096-Bit Serial EEPROM with Data Protect and Sequential Read

General Description

The NM93CS06/CS46/CS56/CS66 devices are 256/1024/2048/4096 bits, respectively, of CMOS non-volatile electrically erasable memory divided into 16/64/128/256 16-bit registers. Selected registers can be protected against data modification by programming the Protect Register with the address of the first register to be protected against data modification (all registers greater than, or equal to, the selected address are then protected from further change). Additionally, this address can be "locked" into the device, making all future attempts to change data impossible. These devices are fabricated using National Semiconductor floating-gate CMOS process for high reliability, high endurance and low power consumption. The NM93CSXX Familly is offered in both SO and TSSOP packages for small space considerations.

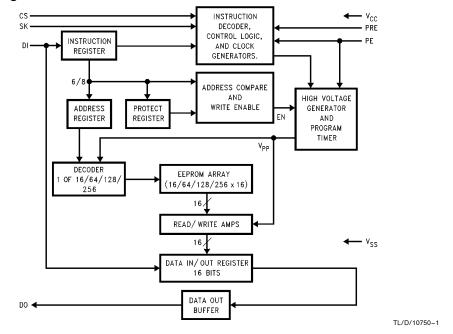
The EEPROM interfacing is MICROWIRE compatible providing simple interfacing to standard microcontrollers and microprocessors. There are a total of 10 instructions, 5 which operate on the EEPROM memory, and 5 which operate on the Protect Register. The memory instructions are

READ, WRITE, WRITE ALL, WRITE ENABLE, and WRITE DISABLE. The Protect register instructions are PRREAD, PRWRITE, PRENABLE, PRCLEAR, and PRDISABLE.

Features

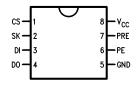
- Write protection in a user defined section of memory
- Sequential register read
- \blacksquare Typical active current of 200 μA and standby current of 10 μA
- No erase required before write
- Reliable CMOS floating gate technology
- MICROWIRE compatible serial I/O
- Self timed write cycle
- Device status during programming mode
- 40 year data retention
- Endurance: 10⁶ data changes
- 4.5V to 5.5V operation in all modes of operation
- Packages available: 8-pin SO, 8-pin DIP, 8-pin TSSOP

Block Diagram



Connection Diagram

Dual-In-Line Package (N) 8-Pin SO (M8) and 8-Pin TSSOP (MT8)



Top View NS Package Number N08E, M08A and MTC08

Pin Names

CS	Chip Select				
SK	Serial Data Clock				
DI	Serial Data Input				
DO	Serial Data Output				
GND	Ground				
PE	Program Enable				
PRE	Protect Register Enable				
V _{CC} Power Supply					

Ordering Information

Commercial Temp. Range (0°C to $\,+\,70^{\circ}$ C)

TL/D/10750-2

Order Number

NM93CS06N/NM93CS46N/NM93CS56N/NM93CS66N NM93CS06M8/NM93CS46M8/NM93CS56M8/NM93CS66M8 NM93CS46MT8/NM93CS56MT8/NM93CS66MT8

Extended Temp. Range (-40°C to $+85^{\circ}\text{C}$)

Order Number

NM93CS06EN/NM93CS46EN/NM93CS56EN/NM93CS66EN NM93CS06EM8/NM93CS46EM8/NM93CS56EM8/NM93CS66EM8 NM93CS46EMT8/NM93CS56EMT8/NM93CS66EMT8

Automotive Temp. Range (-40° C to $+125^{\circ}$ C)

Order Number

NM93CS06VN/NM93CS46VN/NM93CS56VN/NM93CS66VN NM93CS06VM8/NM93CS46VM8/NM93CS56VM8/NM93CS66VM8 NM93CS46VMT8/NM93CS56VMT8/NM93CS66VMT8

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Ambient Storage Temperature -65°C to +150°C

All Input or Output Voltages
with Respect to Ground

-65°C to +150°C
+6.5V to -0.3V

Operating Conditions

Ambient Operating Temperature NM93CSxx NM93CSxxE NM93CSxxV

Power Supply (V_{CC})

0°C to +70°C -40°C to +85°C -40°C to +125°C 4.5V to 5.5V

DC and AC Electrical Characteristics $V_{\text{CC}} = 4.5 \text{V}$ to 5.5 V unless otherwise specified

Symbol	Parameter	Part Number	Conditions	Min	Max	Units
ICCA	Operating Current	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V	$CS = V_{IH}, SK = 1.0 MHz$ SK = 1.0 MHz		1 1	mA
Iccs	Standby Current	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS06E/V	CS = V _{IL}		50 50	μΑ
I _{IL} I _{OL}	Input Leakage Output Leakage		V _{IN} = 0V to V _{CC} (Note 3)		±-1	μΑ
$V_{IL} \ V_{IH}$	Input Low Voltage Input High Voltage			-0.1 2	0.8 V _{CC} + 1	V
V _{OL1} V _{OH1}	Output Low Voltage Output High Voltage		$I_{OL}=2.1 \text{ mA}$ $I_{OH}=-400 \mu\text{A}$	2.4	0.4	V
V _{OL2} V _{OH2}	Output Low Voltage Output High Voltage		$I_{OL} = 10 \mu A$ $I_{OH} = -10 \mu A$	V _{CC} - 0.2	0.2	V
fsk	SK Clock Frequency	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V	(Note 4)	0 0	1 1	MHz
tskH	SK High Time	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V		250 300		ns
tskL	SK Low Time			250		ns
t _{SKS}	SK Setup Time		SK Must Be at V _{IL} for t _{SKS} before CS goes high	50 50 100		ns
tcs	Minimum CS Low Time	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V	(Note 2)	250 250		ns
t _{CSS}	CS Setup Time			100		ns
t _{PRES}	PRE Setup Time	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V		50 50		ns
t _{DH}	DO Hold Time			70		ns
t _{PES}	PE Setup Time	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V		50 50		ns
t _{DIS}	DI Setup Time	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V		100 100		ns
t _{CSH}	CS Hold Time			0		ns

$\textbf{DC and AC Electrical Characteristics} \ \textit{V}_{CC} = 4.5 \textit{V to 5.5 V unless otherwise specified (Continued)}$

Symbol	Parameter	Part Number	Conditions	Min	Max	Units
t _{PEH}	PE Hold Time	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V		250 250		ns
t _{PREH}	PRE Hold Time			50		ns
t _{DIH}	DI Hold Time			20		ns
t _{PD1}	Output Delay to "1"	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V			500 500	ns
t _{PD0}	Output Delay to "0"	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V			500 500	ns
t _{SV}	CS to Status Valid	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V			500 500	ns
t _{DF}	CS to DO in TRI-STATE®	NM93CS06-NM93CS66 NM93CS06E/V-NM93CS66E/V	CS = V _{IL}		100 100	ns
t _{WP}	Write Cycle Time				10	ms

Capacitance $T_A = 25^{\circ}C$, f = 1 MHz

Symbol	Test	Тур	Max	Units
C _{OUT}	Output Capacitance		5	pF
C _{IN}	Input Capacitance		5	pF

Note 1: Stress ratings above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: CS (Chip Select) must be brought low (to V_{IL}) for an interval of t_{CS} in order to reset all internal device registers (device reset) prior to beginning another opcode cycle (this is shown in the opcode diagrams in the following pages).

Note 3: Typical leakage values are in the 20 nA range.

Note 4: The shortest allowable SK clock period = $1/f_{SK}$ (as shown under the f_{SK} parameter). Maximum SK clock speed (minimum SK period) is determined by the interaction of several AC parameters stated in the datasheet. Within this SK period, both t_{SKH} and t_{SKL} limits must be observed. Therefore, it is not allowable to set $1/f_{SK} = t_{SKH}$ (minimum) $+ t_{SKL}$ (minimum) for shorter SK cycle time operation.

AC Test Conditions

V _{CC} Range	V _{IL} /V _{IH} V _{IL} /V _{IH} Input Levels Timing Level		V _{OL} /V _{OH} Timing Level	I _{OL} /I _{OH}	
$\begin{array}{l} \text{4.5V} \leq \text{V}_{\text{CC}} \\ \leq \text{5.5V} \\ \text{(TTL Levels)} \end{array}$	0.4V/2.4V	1.0V/2.0V	0.4V/2.4V	−2.1 mA/ 0.4 mA	

Output Load: 1 TTL Gate ($C_L = 100 \text{ pF}$)

Functional Description

The NM93CSxx EEPROM Family has 10 instructions as described below. All Data-In signals are clocked into the device on the low-to-high SK transition.

Read and Sequential Register Read (READ):

The READ instruction outputs serial data on the D0 pin. After a READ instruction is received, the instruction and address are decoded, followed by data transfer from the selected memory register into a 16-bit serial-out shift register. A dummy bit (logical 0) precedes the 16-bit data output string. Output data changes are initiated by a low to high transition of the SK clock. In the **sequential register read** mode of operation, the memory automatically cycles to the next register after each 16 data bits are clocked out. The dummy-bit is suppressed in this mode and a continuous string of data is obtained.

Write Enable (WEN):

When V_{CC} is applied to the part, it "powers up" in the Write Disable (WDS) state. Therefore, all programming modes must be preceded by a Write Enable (WEN) instruction. Once a Write Enable instruction is executed, programming remains enabled until a Write Disable (WDS) instruction is executed or V_{CC} is completely removed from the part.

Write (WRITE):

The WRITE instruction is followed by 16 bits of data to be written into the specified address. After the last bit of data is put on the data-in (DI) pin, CS must be brought low before the next rising edge of the SK clock. This falling edge of the CS initiates the self-timed programming cycle. The PE pin MUST be held high while loading the WRITE instruction, however, after loading the WRITE instruction the PE pin becomes a "don't care". The D0 pin indicates the READY/BUSY status of the chip if CS is brought high after the $t_{\rm CS}$ interval. D0 = logical 0 indicates that programming is still in progress. D0 = logical 1 indicates that the register at the address specified in the instruction has been written with the data pattern specified in the instruction and the part is ready for another instruction.

Write All (WRALL):

The WRALL instruction is valid only when the Protect Register has been cleared by executing a PRCLEAR instruction. The WRALL instruction will simultaneously program all registers with the data pattern specified in the instruction. Like the WRITE instruction, the PE pin **MUST** be held high while loading the WRALL instruction, however, after loading the instruction the PE pin becomes a "don't care". As in the WRITE mode, the DO pin indicates the READY/BUSY status of the chip if CS is brought high after the ${\rm tcs}$ interval. This function is DISABLED if the Protect Register is in use to lock out a section of memory.

Write Disable (WDS):

To protect against accidental data disturb, the Write Disable (WDS) instruction disables all programming modes and should follow all programming operations. Execution of a READ instruction is independent of both the WEN and WDS instructions.

Note: For all Protect Register Operations: If the PRE pin is not held at V_{IH} , all instructions will be applied to the EEPROM array, rather than the Protect Register.

Protect Register Read (PRREAD):

The PRREAD instruction outputs the address stored in the Protect Register on the DO pin. The PRE pin **MUST** be held high while loading the instruction sequence. Following the PRREAD instruction the 6- or 8-bit address stored in the memory protect register is transferred to the serial out shift register. As in the READ mode, a dummy bit (logical 0) precedes the 6- or 8-bit address string.

Protect Register Enable (PREN):

The PREN instruction is used to enable the PRCLEAR, PRWRITE, and PRDS modes. Before the PREN mode can be entered, the part must be in the Write Enable (WEN) mode. Both the PRE and PE pins **MUST** be held high while loading the instruction sequence.

Note that a PREN instruction must **immediately** precede a PRCLEAR, PRWRITE, or PRDS instruction.

Protect Register Clear (PRCLEAR):

The PRCLEAR instruction clears the address stored in the Protect Register and, therefore, enables **all** registers for the WRITE and WRALL instruction. The PRE and PE pins **must** be held high while loading the instruction sequence, however, after loading the PRCLEAR instruction the PRE and PE pins become "don't care". Note that a PREN instruction must **immediately** precede a PRCLEAR instruction.

Please note that the PRCLEAR instruction and the PRWRITE instruction will both program the Protect Register with all 1s. However, the PRCLEAR instruction will allow the LAST register to be programmed, whereas the PRWRITE instruction = all 1s will PREVENT the last register from being programmed. In addition, the PRCLEAR instruction will allow the use of the WRALL command, where the PRWRITE = all 1s will lock out the Bulk programming opcode.

Protect Register Write (PRWRITE):

The PRWRITE instruction is used to write into the Protect Register the address of the first register to be protected. After the PRWRITE instruction is executed, all memory registers whose addresses are greater than or equal to the address specified in the Protect Register are protected from the WRITE operation. Note that before executing a PRWRITE instruction the Protect Register must first be cleared by executing a PRCLEAR operation and that the PRE and PE pins **must** be held high while loading the instruction, however, after loading the PRWRITE instruction the PRE and PE pins become 'don't care'. Note that a PREN instruction must **immediately** precede a PRWRITE instruction.

Protect Register Disable (PRDS):

The PRDS instruction is a **ONE** TIME ONLY instruction which renders the Protect Register unalterable in the future. Therefore, the specified registers become **PERMANENTLY** protected against data changes. As in the PRWRITE instruction the PRE and PE pins **must** be held high while loading the instruction, and after loading the PRDS instruction the PRE and PE pins become "don't care".

Note that a PREN instruction must **immediately** precede a PRDS instruction.

Instruction Set for the NM93CS06 and NM93CS46 Op Code Instruction Address Data PRE Comments READ 1 10 A5-A0 0 Χ Reads data stored in memory, starting at specified address. WEN 1 00 11XXXX 0 Enable all programming modes. 1 WRITE 1 A5-A0 D15-D0 0 Writes address if unprotected. 01 1 WRALL 1 01XXXX D15-D0 0 1 Writes all registers. Valid only when Protect Register is cleared. WDS 1 00 00XXXX 0 Х Disables all programming modes. PRREAD 1 10 XXXXXX 1 Х Reads address stored in Protect Register. PREN 11XXXX Must immediately precede PRCLEAR, PRWRITE, and 1 00 1 1 PRDS instructions. Clears the Protect Register so that no registers are **PRCLEAR** 111111 1 11 1 1 protected from WRITE. Programs address into Protect Register. Thereafter, **PRWRITE** 01 A5-A0 memory addresses \geq the address in Protect Register are protected from WRITE. PRDS 000000 ONE TIME ONLY instruction after which the address in the 1 00 1 1 Protect Register cannot be altered.

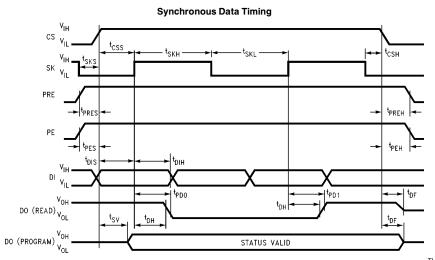
Note: Address bits A5 and A4 become "Don't Care" for the NM93CS06.

Instruction Set for the NM93CS56 and NM93CS66

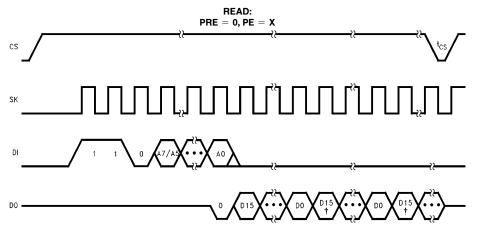
Instruction	SB	Op Code	Address	Data	PRE	PE	Comments
READ	1	10	A7-A0		0	Х	Reads data stored in memory, starting at specified address.
WEN	1	00	11XXXXXX		0	1	Enable all programming modes.
WRITE	1	01	A7-A0	D15-D0	0	1	Writes address if unprotected.
WRALL	1	00	01XXXXXX	D15-D0	0	1	Writes all registers. Valid only when Protect Register is cleared.
WDS	1	00	00XXXXXX		0	Х	Disables all programming modes.
PRREAD	1	10	XXXXXXX		1	Х	Reads address stored in Protect Register.
PREN	1	00	11XXXXXX		1	1	Must immediately precede PRCLEAR, PRWRITE, and PRDS instructions.
PRCLEAR	1	11	11111111		1	1	Clears the "protect register" so that no registers are protected from WRITE.
PRWRITE	1	01	A7-A0		1	1	Programs address into Protect Register. Thereafter, memory addresses ≥ the address in Protect Register are protected from WRITE.
PRDS	1	00	00000000		1	1	ONE TIME ONLY instruction after which the address in the Protect Register cannot be altered.

Note: Address bit A7 becomes "Don't Care" for the NM93CS56.



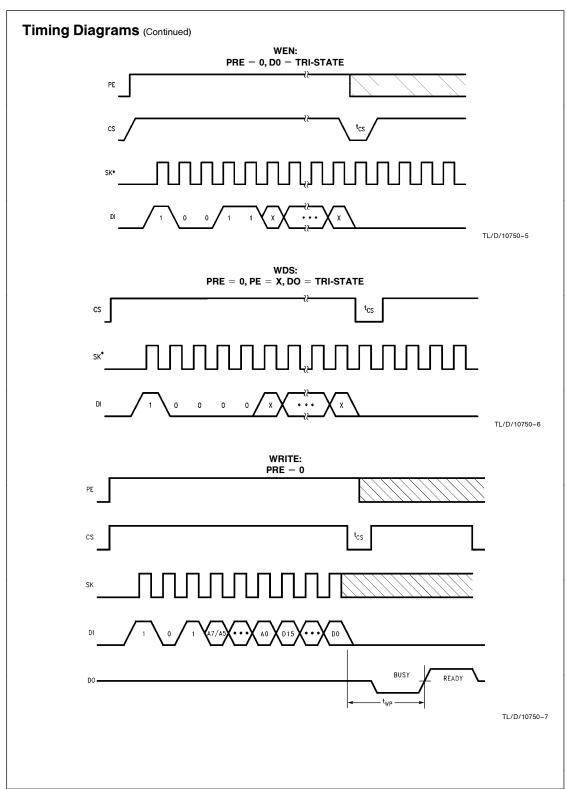


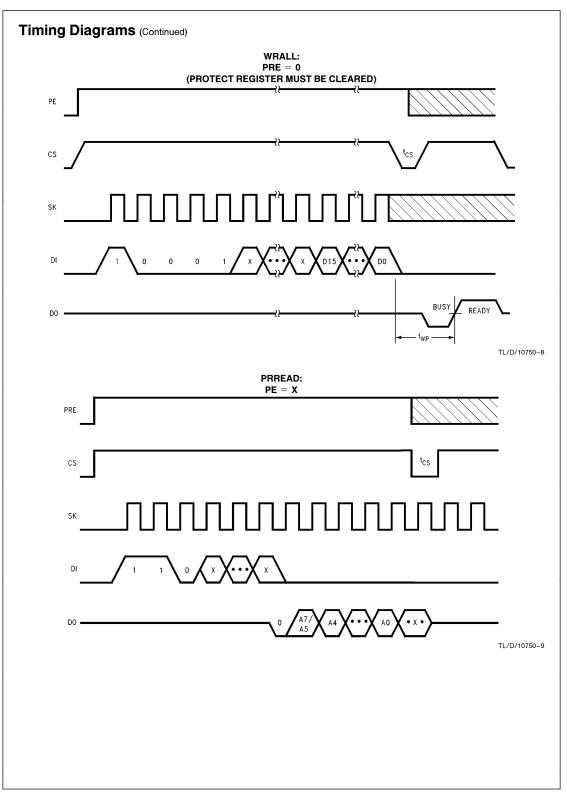
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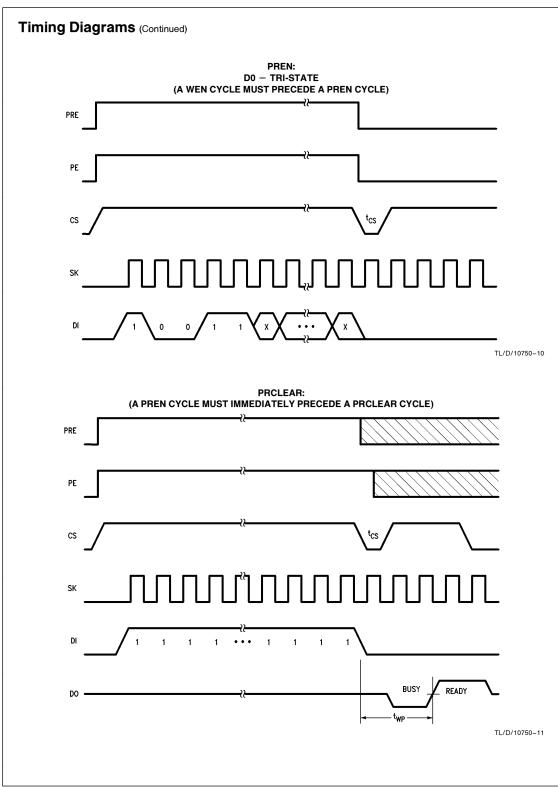


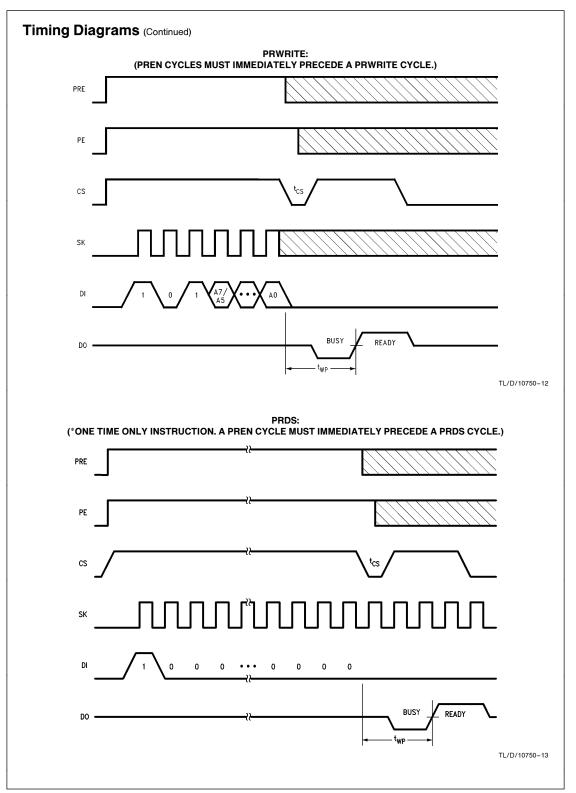
 $^{\dagger}\text{The}$ memory automatically cycles to the next register with continued clocking of SK.

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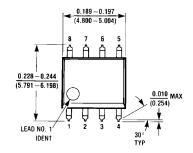


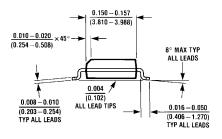


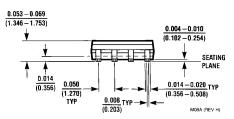




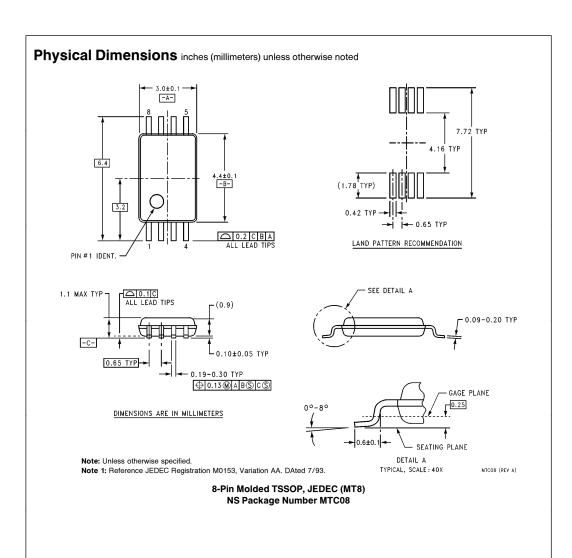
Physical Dimensions inches (millimeters) unless otherwise noted



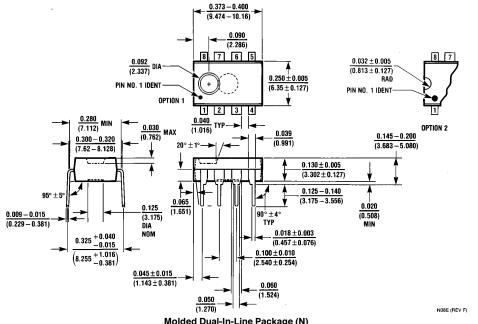




Molded Package, Small Outline, 0.15 Wide, 8-Lead (M8) NS Package Number M08A







Molded Dual-In-Line Package (N) NS Package Number N08E

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National Semiconductor

National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

http://www.national.com

National Semiconductor Europe

Fax: +49 (0) 180-530 85 86 Fax: +49 (0) 180-530 so so Email: europe.support@nsc.com Deutsch Tel: +49 (0) 180-530 85 85 English Tel: +49 (0) 180-532 78 32 Français Tel: +49 (0) 180-532 95 58 Italiano Tel: +49 (0) 180-534 16 80

National Semiconductor

Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd. Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2308
Fax: 81-043-299-2408